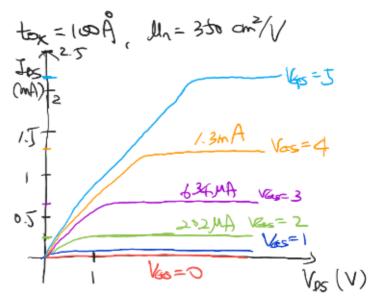
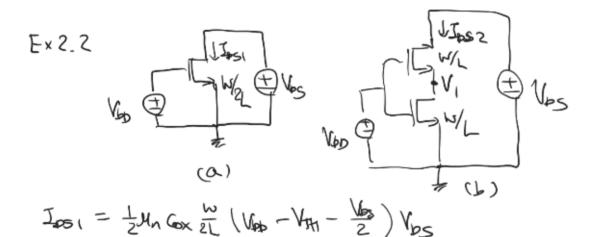
디집 HW3

Ex 2.1
$$W/L = 4/2 \lambda$$

 $Vth = 0.7$ $V_{ds} = 0.05V$
 $J_{d} = \frac{1}{2}Jh_{\lambda} \left(b_{x} \frac{U}{L} \left(V_{ds} - V_{tot} \right)^{2} \right)$
 $\int_{0}^{\infty} \frac{1}{2}Jh_{\lambda} \left(b_{x} \frac{U}{L} \left(V_{ds} - V_{tot} \right)^{2} \right)$





$$I_{05} = \frac{1}{2} N_{11} (o_{11} \frac{U}{L} (V_{00} - V_{011} - \frac{V_{1}}{2}) V_{1}$$

$$= \frac{1}{2} N_{11} (o_{11} \frac{U}{L} [(V_{00} - V_{11}) - V_{011} - \frac{(V_{05} - V_{1})}{2}] (V_{05} - V_{1})$$

$$\therefore V_{1} = (V_{00} - V_{011}) - \int (V_{00} - V_{011})^{2} - (V_{00} - V_{011} - \frac{V_{01}}{2}) V_{05}$$

Ex 2.3 (a) \(\sigma\) estect > \(\text{ 43449}\) 856.

(4) \(\text{U} \) 139 \(\text{S} \) 912 \(\text{Tr} \) other tody effect > \(\text{46145}\).

(b) \(\text{V} \) \(\text{S} = 0 - V, \quad \text{1} \) 284801.

body effect + 22 37, 1997 - 87-249 Jass > Ips 2 4819.

$$E_{x}2.4 \quad q_{om} \text{ tr} \rightarrow 16 \text{ Å} - 1 \text{ to}_{x} = 25 \text{ CL}.$$

$$C_{g} = ?$$

$$C = E \frac{A}{d}$$

$$G = \frac{E \cdot L}{to_{x}} = \frac{39 \cdot 8.85 \cdot 15^{14} \cdot 90 - 15^{2}}{16 \cdot 15^{4}}$$

$$\left[\frac{F(a_{1} - c_{1})}{y_{1}}\right] 2HM$$

Ex2.5 0.6 Jun process $C_{db} = ?$ $V_D = D$ and t = 0.720M, $V_D = 0$, $CJ = 0.42 fF/Jun^2$, MJ = 0.44, CJSW = 0.33 fF/Jun MJSW = 0.12, $V_O = 0.98$

Cj= 1.94 fF/um

Minimum 52e diffusion cutzet => 4×5 > or $1-2\times15$ μ m² $A = 1.8 \mu$ m², Perineter = $5-4 \mu$ m

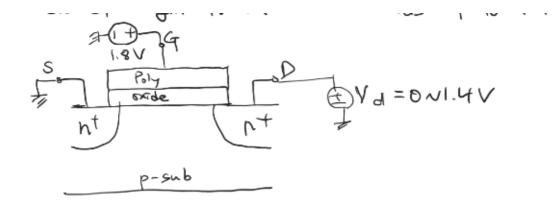
$$C_{db}(0V) = (1.8)(0.42) + (5.4)(0.33) = 2.54fF$$

$$C_{db}(5V) = (1.8)(0.42) \cdot (1 + \frac{5}{0.98})^{-0.04}$$

$$+ (5.4)(0.33) \left(1 + \frac{7}{0.98}\right)^{-0.12} = 1.08fF$$

Problem. NMOS Vg=1.8V, Vt=0.4V

chamel length=180nm Vas 4 to 1.4V



0 397 Vgs >Vt 2K1 |mear 303016 825 Vgs-Vt ≥ Vgs >K1 trisde 8030K1 824 Vd =0 °2 2012, Channel °1 Nt 100 mt 32/8 Vd>+ 312472 channel 1 2507219. Nt 100 mt 24244, Channel potential 24073.